NSN 5961-01-084-0816

Fiig: A110a0



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-084-0816 **Inclosure Material:** Metal **Overall Length:** 0.405 inches **Overall Diameter:** Between 0.424 inches and 0.437 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-4 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No